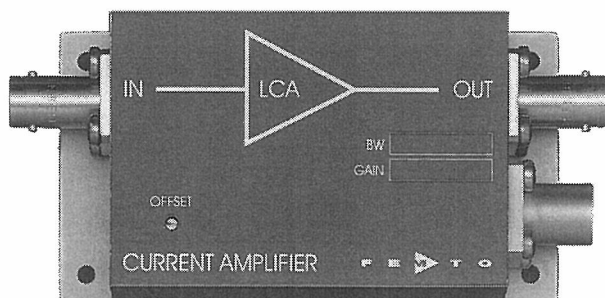


Ultra-Low-Noise Current Amplifier

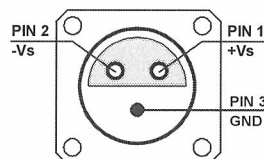


Features	<ul style="list-style-type: none">• Bandwidth and Frequency Response Independent of Detector-Capacitance (up to 10 nF)• Extremely Low Noise, 6.5 fA/√Hz Equivalent Input Noise Current• Bandwidth DC ... 4 kHz• Transimpedance (Gain) 1 x 10⁹ V/A																																																									
Applications	<ul style="list-style-type: none">• Photodiode- and Photomultiplier-Amplifier• Spectroscopy• Charge-Amplifier• Ionisation Detectors• Preamplifier for Lock-Ins, A/D-Converters, etc.																																																									
Specifications	<table><tr><td></td><td><i>Test Conditions</i></td><td><i>V_s = ± 15 V, T_a = 25°C</i></td></tr><tr><td rowspan="2">Gain</td><td>Transimpedance</td><td>1 x 10⁹ V/A (>10 kΩ Load)</td></tr><tr><td>Accuracy</td><td>± 1%</td></tr><tr><td rowspan="4">Frequency Response</td><td>Lower Cut-Off Frequency</td><td>DC</td></tr><tr><td>Upper Cut-Off Frequency</td><td>4 kHz (- 3 dB)</td></tr><tr><td>Rise- / Fall-Time</td><td>100 μs (10% - 90%)</td></tr><tr><td>Gain Flatness</td><td>± 0.1 dB</td></tr><tr><td rowspan="8">Input</td><td>Equ. Input Noise Current</td><td>6.5 fA/√Hz (@ 1 kHz)</td></tr><tr><td>Equ. Input Noise Voltage</td><td>5 nV/√Hz (@ 1 kHz)</td></tr><tr><td>Input Bias Current</td><td>2 pA typ.</td></tr><tr><td>Input Bias Current Drift</td><td>Factor 1.7 / 10 K</td></tr><tr><td>Offset Current Compensation</td><td>± 3 nA, Adjustable by Offset-Trimpot</td></tr><tr><td>Max. Input Current</td><td>± 10 nA (Linear Amplification)</td></tr><tr><td>Input Offset Voltage</td><td>< 1 mV</td></tr><tr><td>DC Input Impedance</td><td>50 Ω (Virtual) // 5 pF</td></tr><tr><td rowspan="3">Output</td><td>Output Voltage</td><td>± 10 V (>10 kΩ Load)</td></tr><tr><td>Output Impedance</td><td>50 Ω (Terminate with >10 kΩ for best Performance)</td></tr><tr><td>Max. Output Current</td><td>± 10 mA (Linear Amplification)</td></tr><tr><td rowspan="2">Power Supply</td><td>Supply Voltage</td><td>± 15 V</td></tr><tr><td>Supply Current</td><td>± 40 mA typ.</td></tr><tr><td rowspan="2">Case</td><td>Weight</td><td>210 gr. (0.5 lbs)</td></tr><tr><td>Material</td><td>AlMg4.5Mn, nickel-plated</td></tr><tr><td rowspan="2">Temperature Range</td><td>Storage Temperature</td><td>-40 ... +100 °C</td></tr><tr><td>Operating Temperature</td><td>0 ... +60 °C</td></tr></table>			<i>Test Conditions</i>	<i>V_s = ± 15 V, T_a = 25°C</i>	Gain	Transimpedance	1 x 10 ⁹ V/A (>10 kΩ Load)	Accuracy	± 1%	Frequency Response	Lower Cut-Off Frequency	DC	Upper Cut-Off Frequency	4 kHz (- 3 dB)	Rise- / Fall-Time	100 μs (10% - 90%)	Gain Flatness	± 0.1 dB	Input	Equ. Input Noise Current	6.5 fA/√Hz (@ 1 kHz)	Equ. Input Noise Voltage	5 nV/√Hz (@ 1 kHz)	Input Bias Current	2 pA typ.	Input Bias Current Drift	Factor 1.7 / 10 K	Offset Current Compensation	± 3 nA, Adjustable by Offset-Trimpot	Max. Input Current	± 10 nA (Linear Amplification)	Input Offset Voltage	< 1 mV	DC Input Impedance	50 Ω (Virtual) // 5 pF	Output	Output Voltage	± 10 V (>10 kΩ Load)	Output Impedance	50 Ω (Terminate with >10 kΩ for best Performance)	Max. Output Current	± 10 mA (Linear Amplification)	Power Supply	Supply Voltage	± 15 V	Supply Current	± 40 mA typ.	Case	Weight	210 gr. (0.5 lbs)	Material	AlMg4.5Mn, nickel-plated	Temperature Range	Storage Temperature	-40 ... +100 °C	Operating Temperature	0 ... +60 °C
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Ultra-Low-Noise Current Amplifier

Connectors

Input	BNC
Output	BNC
Power Supply	LEMO Series 1S, 3-pin Fixed Socket Pin 1: + 15V Pin 2: - 15V Pin 3: GND



Application Diagrams

Photo Detector Biasing in Photovoltaic Mode:
Use for Low Speed Applications and Minimum Dark Current.

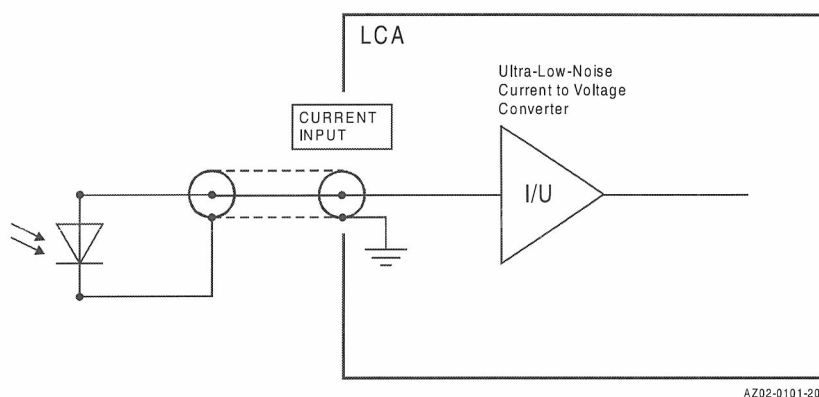
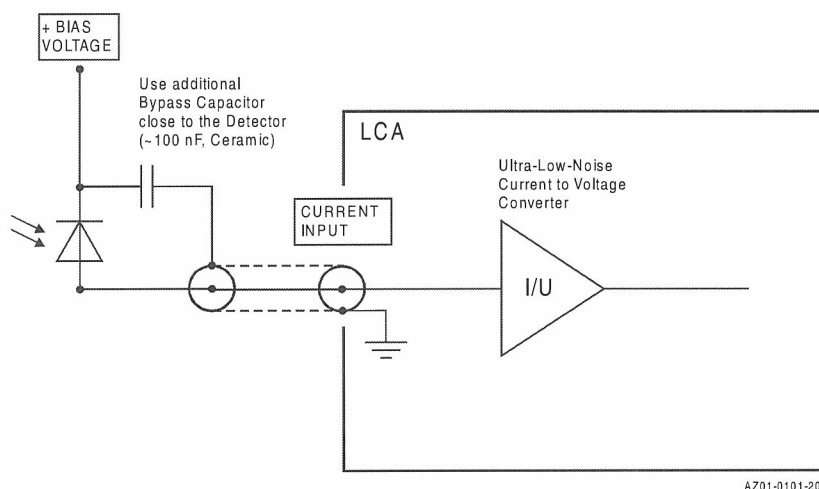
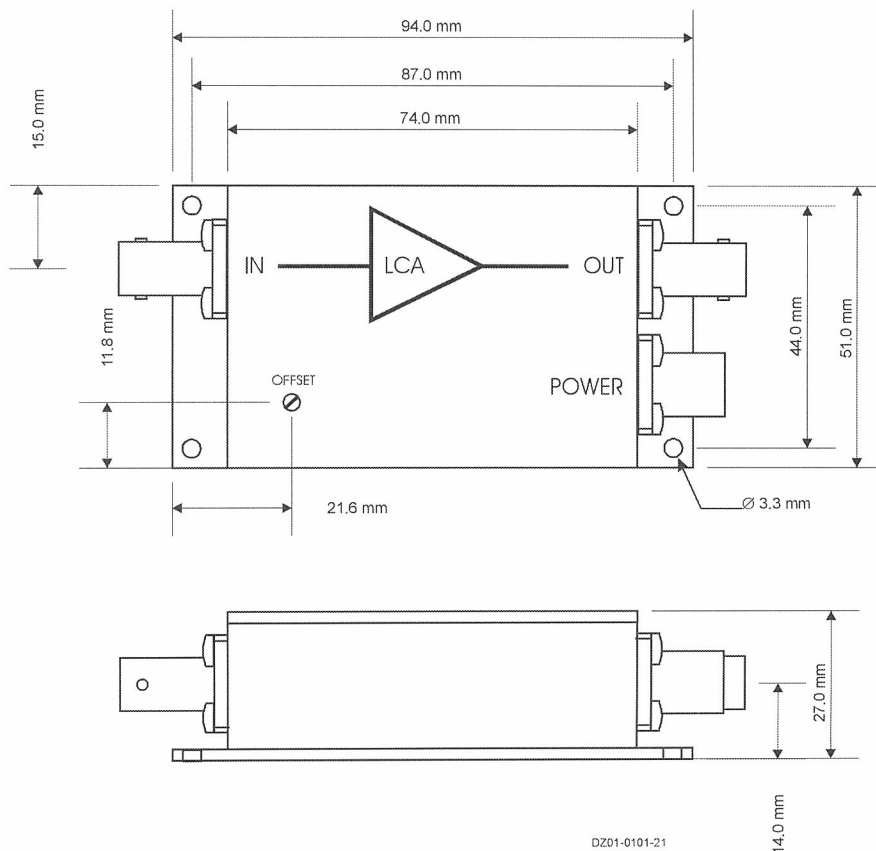


Photo Detector Biasing in Photoconductive Mode:
Use for Fast Applications and if More Dark Current is Tolerable.
Bias Voltage Decreases Detector Capacitance.



Ultra-Low-Noise Current Amplifier

Dimensions



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